

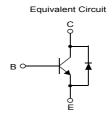
FJU5304D

High Voltage Fast Switching Transistor

Features

- Built-in Free Wheeling Diode
- · Wide Safe Operating Area
- Small Variance in Storage Time
- · Suitable for Electronic Ballast Application





Absolute Maximum Ratings T_C = 25°C unless otherwise noted

| Symbol | Parameter | Value | Units |
|------------------|---|-----------|-------|
| V _{CBO} | Collector-Base Voltage | 700 | V |
| V _{CEO} | Collector-Emitter Voltage | 400 | V |
| V _{EBO} | Emitter-Base Voltage | 12 | V |
| I _C | Collector Current (DC) | 4 | Α |
| I _{CP} | * Collector Current (Pulse) | 8 | Α |
| I _B | Base Current (DC) | 2 | Α |
| I _{BP} | * Base Current (Pulse) | 4 | Α |
| P _C | Collector Dissipation (T _C = 25°C) | 30 | W |
| T _J | Junction Temperature | 150 | °C |
| T _{STG} | Storage Temperature | -55 ~ 150 | °C |

^{*} Pulse Test: PW = $300\mu s$, Duty Cycle = 2% Pulsed

Package Marking and Ordering Information

| Device Marking | Device | Package | Reel Size | Tape Width | Quantity |
|-----------------------|------------|---------|-----------|------------|----------|
| J5304D | FJU5304DTU | I-PAK | - | - | 75 |

Electrical Characteristics T_C = 25°C unless otherwise noted

| Symbol | Parameter | Conditions | Min. | Тур. | Max | Units |
|----------------------|--------------------------------------|--|---------|------|-----|-------|
| BV _{CBO} | Collector-Base Breakdown Voltage | I _C = 1mA, I _E = 0 | 700 | | | V |
| BV _{CEO} | Collector-Emitter Breakdown Voltage | I _C = 5mA, I _B = 0 | 400 | | | V |
| BV _{EBO} | Emitter-Base Breakdown Voltage | I _E = 1mA, I _C = 0 | 12 | | | V |
| I _{CES} | Collector Cut-off Current | V _{CB} = 700V, I _E = 0 | | | 100 | μА |
| I _{CEO} | Collector Cut-off Current | V _{CB} = 400V, I _B = 0 | | | 250 | μΑ |
| I _{EBO} | Emitter Cut-off Current | V _{EB} = 12V, I _C = 0 | | | 1 | mA |
| h _{FE} | DC Current Gain | V _{CE} = 5V, I _C = 10mA V _{CE} = 5V, I _C = 2.0A | 10 8 | | 40 | |
| V _{CE(sat)} | Collector-Emitter Saturation Voltage | I _C = 0.5A, I _B = 0.1A | | | 0.7 | V |
| | | I _C = 1.0A, I _B = 0.2A | | | 1.0 | V |
| | | I _C = 2.5A, I _B = 0.5A | | | 1.5 | V |
| V _{BE(sat)} | Base-Emitter Saturation Voltage | I _C = 0.5A, I _B = 0.1A | | | 1.1 | V |
| | | I _C = 1.0A, I _B = 0.2A | | | 1.2 | V |
| | | I _C = 2.5A, I _B = 0.5A | | | 1.3 | V |
| t _{STG} | Storage Time | V _{CLAMP} =200V, I _C =2.0A | | 0.6 | | μS |
| t _F | Fall Time | I _{B1} =0.4A, V _{BE} (off)=-5V, L=200μH | | 0.1 | | μS |
| t _{STG} | Storage Time | V _{CC} =250V, I _C =2.0A | | | 2.9 | μS |
| t _F | Fall Time | I _{B1} =0.4A, I _{B2} =-0.4A, T _P =30μs | | 0.2 | | μS |

Typical Performance Characteristics

Figure 1. Static Characterstic

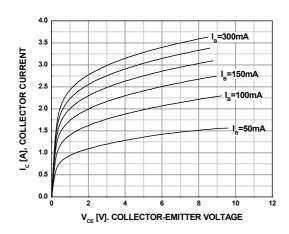


Figure 2. DC Current Gain

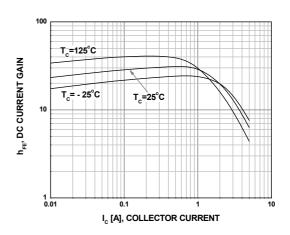


Figure 3. Collector-Emitter Saturation Voltage

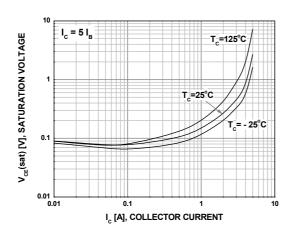


Figure 4. Base-Emitter Saturation Voltage

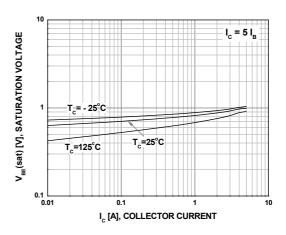


Figure 5. Resistive Load Switching Time

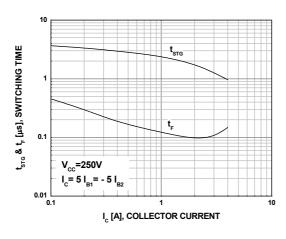
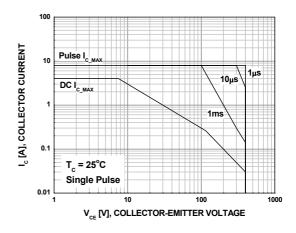


Figure 6. Forward Biased Safe Operating Area



Typical Performance Characteristics (Continued)

Figure 7. Reverse Biased Safe Operating Area

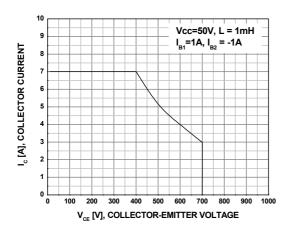
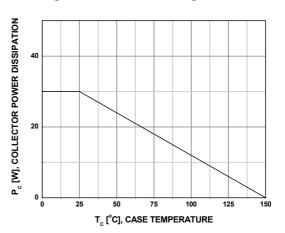
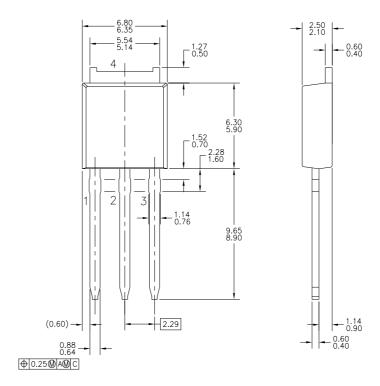


Figure 8. Power Derating Curve



Mechanical Dimensions

I-PAK





Dimensions in Millimeters

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Rev. I13